

CD4093B Types

CMOS

Quad 2-Input NAND Schmitt Triggers

High-Voltage Types (20 Volt Rating)

■ CD4093B consists of four Schmitt-trigger circuits. Each circuit functions as a two-input NAND gate with Schmitt-trigger action on both inputs. The gate switches at different points for positive- and negative-going signals. The difference between the positive voltage (V_p) and the negative voltage (V_N) is defined as hysteresis voltage (V_H) (see Fig. 2).

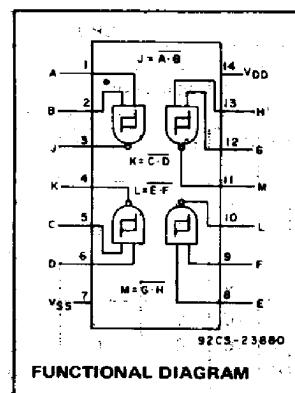
The CD4093B types are supplied in 14-lead hermetic dual-in-line ceramic packages (D and F suffixes), 14-lead dual-in-line plastic package (E suffix), and in chip form (H suffix).

Features:

- Schmitt-trigger action on each input with no external components
- Hysteresis voltage typically 0.9 V at $V_{DD} = 5$ V and 2.3 V at $V_{DD} = 10$ V
- Noise immunity greater than 50%
- No limit on input rise and fall times
- Standardized, symmetrical output characteristics
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 μ A at 18 V over full package-temperature range, 100 nA at 18 V and 25°C
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

Applications:

- Wave and pulse shapers
- High-noise-environment systems
- Monostable multivibrators
- Astable multivibrators
- NAND logic

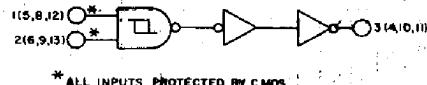


FUNCTIONAL DIAGRAM

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

CHARACTERISTIC	MIN.	MAX.	UNITS
Supply-Voltage Range ($T_A = \text{Full Package-}\text{Temp. Range}$)	3	18	V



* ALL INPUTS PROTECTED BY CMOS PROTECTION NETWORK

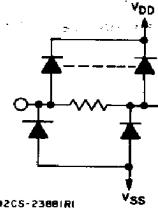


Fig. 1 - Logic diagram—1 of 4 Schmitt triggers.

MAXIMUM RATINGS: Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE; (V_{DD})

Voltages referenced to V_{SS} (Terminal)

INPUT VOLTAGE RANGE, ALL INPUTS

DC INPUT CURRENT, ANY ONE INPUT

POWER DISSIPATION PER PACKAGE (P_D):

For $T_A = -55^\circ\text{C}$ to $+100^\circ\text{C}$

For $T_A = +100^\circ\text{C}$ to $+125^\circ\text{C}$

DEVICE DISSIPATION PER OUTPUT TRANSISTOR

FOR $T_A = \text{FULL PACKAGE-TEMPERATURE RANGE (All Package Types)}$

OPERATING-TEMPERATURE RANGE (T_A)

STORAGE TEMPERATURE RANGE (T_{stg})

LEAD TEMPERATURE (DURING SOLDERING):

At distance $1/16 \pm 1/32$ inch (1.58 \pm 0.79mm) from case for 10s max

-0.5V to +20V

-0.5V to V_{DD} +0.5V

$\pm 10\text{mA}$

500mW

Derate Linearity at 12mW/ $^\circ\text{C}$ to 200mW

100mW

-55°C to +125°C

-65°C to +150°C

+265°C

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STATIC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	CONDITIONS		LIMITS AT INDICATED TEMPERATURES (°C)								UNITS
	V_O (V)	V_{IN} (V)	V_{DD} (V)	-55	-40	+85	+125	MIN.	TYP.	MAX.	
Quiescent Device Current, I_{DD} Max.	—	0.5	5	1	1	30	30	—	0.02	1	mA
	—	0.10	10	2	2	60	60	—	0.02	2	
	—	0.15	15	4	4	120	120	—	0.02	4	
	—	0.20	20	20	20	600	600	—	0.04	20	
Positive Trigger Threshold Voltage V_p	—	a	5	2.2	2.2	2.2	2.2	2.2	2.9	—	V
	—	a	10	4.6	4.6	4.6	4.6	4.6	4.6	5.9	
	—	a	15	6.8	6.8	6.8	6.8	6.8	6.8	8.8	
	—	b	5	2.6	2.6	2.6	2.6	2.6	2.6	3.3	
	—	b	10	5.6	5.6	5.6	5.6	5.6	5.6	7	
	—	b	15	6.3	6.3	6.3	6.3	6.3	9.4	—	
Negative Trigger Threshold Voltage V_N	—	a	5	0.9	0.9	0.9	0.9	0.9	1.9	—	V
	—	a	10	2.5	2.5	2.5	2.5	2.5	3.9	—	
	—	a	15	4	4	4	4	4	5.8	—	
	—	b	5	1.4	1.4	1.4	1.4	1.4	2.3	—	
	—	b	10	3.4	3.4	3.4	3.4	3.4	5.1	—	
	—	b	15	4.8	4.8	4.8	4.8	4.8	7.3	—	
V_N Max.	—	a	5	2.8	2.8	2.8	2.8	—	1.9	2.8	V
	—	a	10	5.2	5.2	5.2	5.2	—	3.9	5.2	
	—	a	15	7.4	7.4	7.4	7.4	—	5.8	7.4	
	—	b	5	3.2	3.2	3.2	3.2	—	2.3	3.2	
	—	b	10	6.6	6.6	6.6	6.6	—	5.1	6.6	
	—	b	15	9.6	9.6	9.6	9.6	—	7.3	9.6	
V_H Min.	—	a	5	0.3	0.3	0.3	0.3	0.3	0.9	—	V
	—	a	10	1.2	1.2	1.2	1.2	1.2	2.3	—	
	—	a	15	1.6	1.6	1.6	1.6	1.6	3.5	—	
	—	b	5	0.3	0.3	0.3	0.3	0.3	0.9	—	
	—	b	10	1.2	1.2	1.2	1.2	1.2	2.3	—	
	—	b	15	1.6	1.6	1.6	1.6	1.6	3.5	—	
V_H Max.	—	a	5	1.6	1.6	1.6	1.6	—	0.9	1.6	V
	—	a	10	3.4	3.4	3.4	3.4	—	2.3	3.4	
	—	a	15	5	5	5	5	—	3.5	5	
	—	b	5	1.6	1.6	1.6	1.6	—	0.9	1.6	
	—	b	10	3.4	3.4	3.4	3.4	—	2.3	3.4	
	—	b	15	5	5	5	5	—	3.5	5	

* Input on terminals 1,5,8,12 or 2,6,9,13; other inputs to V_{DD} .

** Input on terminals 1 and 2, 5 and 6, 8 and 9, or 12 and 13; other inputs to V_{DD} .

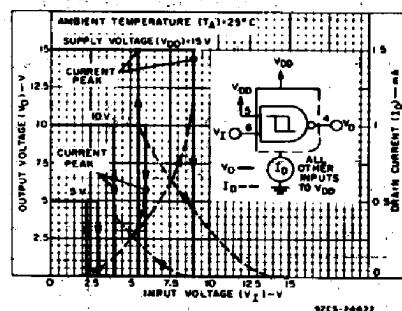


Fig. 4 – Typical current and voltage transfer characteristics.

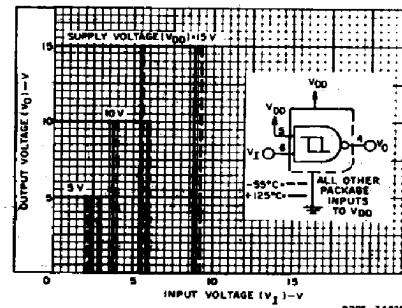


Fig. 5 – Typical voltage transfer characteristics as a function of temperature.

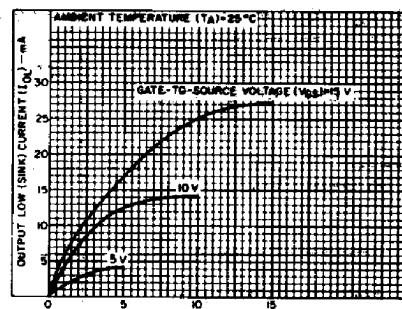


Fig. 6 – Typical output low (sink) current characteristics.

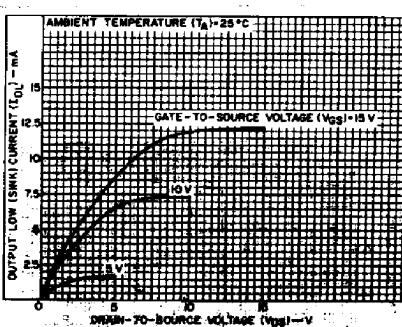


Fig. 7 – Minimum output low (sink) current characteristics.

CD4093B Types

STATIC ELECTRICAL CHARACTERISTICS (CONT'D)

CHARACTERISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)						UNITS		
	V_O (V)	V_{IN} (V)	V_{DD} (V)	-55	-40	+85	+125	+25				
				MIN.	TYP.	MAX.	MIN.	TYP.	MAX.			
Output Low (Sink) Current, I_{OL} Min.	0.4	0.5	5	0.64	0.61	0.42	0.36	0.51	1	—	mA	
	0.5	0.10	10	1.6	1.5	1.1	0.9	1.3	2.6	—		
	1.5	0.15	15	4.2	4	2.8	2.4	3.4	6.8	—		
Output High (Source) Current, I_{OH} Min.	4.6	0.5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	—	mA	
	2.5	0.5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	—		
	9.5	0.10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	—		
Output Voltage Low-Level, V_{OL} Max.	-	0.5	5	0.05			-	0	0.05	V		
	-	0.10	10	0.05			-	0	0.05			
	-	0.15	15	0.05			-	0	0.05			
Output Voltage High-Level, V_{OH} Min.	-	0.5	5	4.95			4.95	5	—	V		
	-	0.10	10	9.95			9.95	10	—			
	-	0.15	15	14.95			14.95	—	—			
Input Current, I_{IN} Max.	-	0.18	18	± 0.1	± 0.1	± 1	± 1	-	$\pm 10^{-5}$	± 0.1	μA	

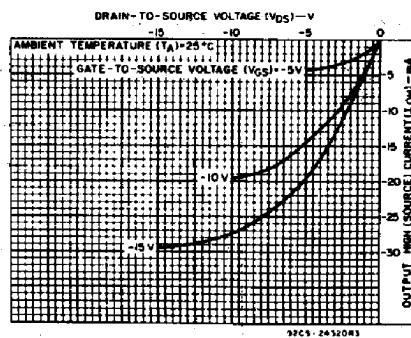


Fig. 8 – Typical output high (source) current characteristics.

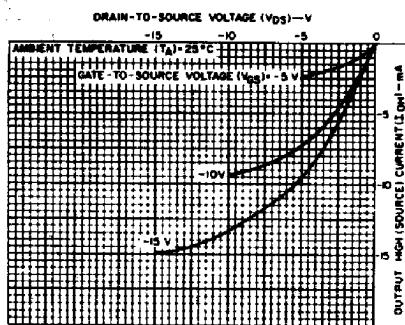


Fig. 9 – Minimum output high (source) current characteristics.

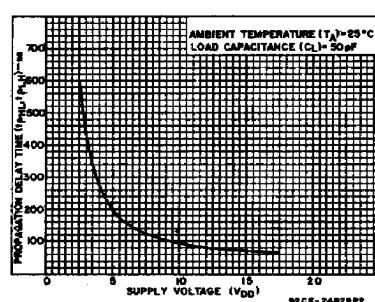


Fig. 10 – Typical propagation delay time vs. supply voltage.

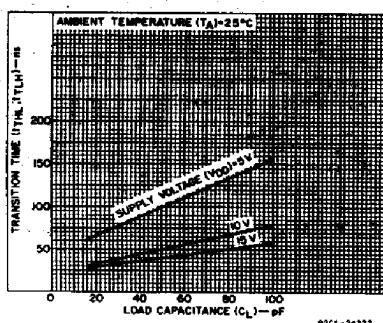


Fig. 11 – Typical transition time vs. load capacitance.

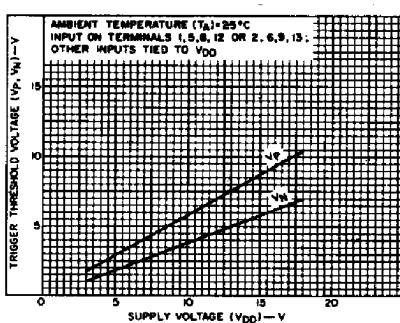


Fig. 12 – Typical trigger threshold voltage vs. V_{DD} .

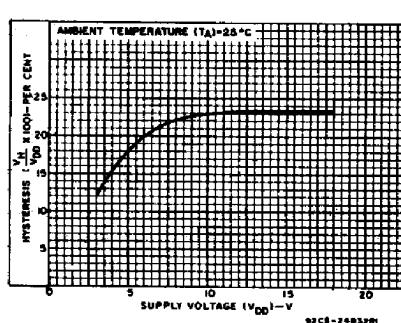
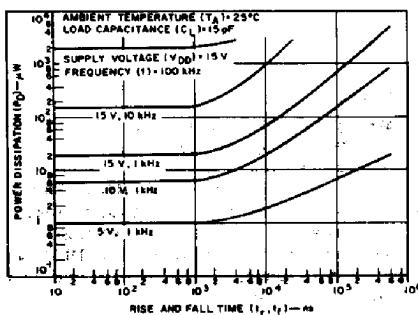
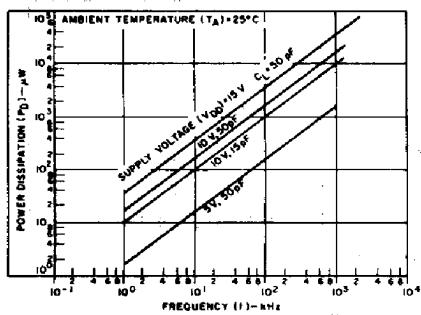
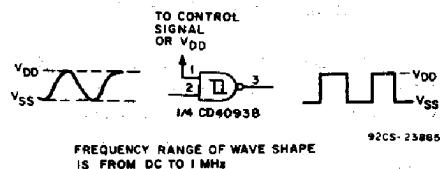


Fig. 13 – Typical per cent hysteresis vs. supply voltage.

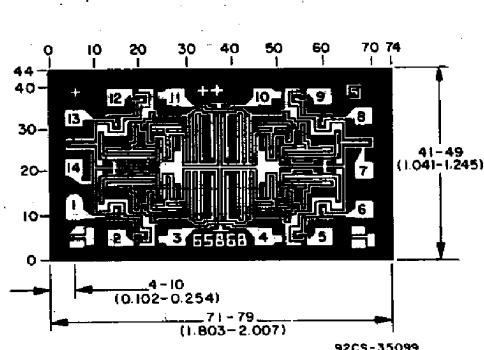
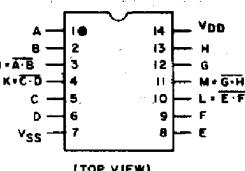
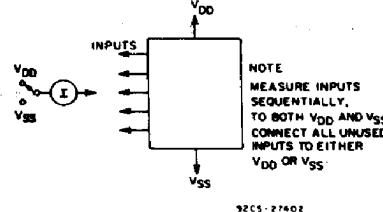
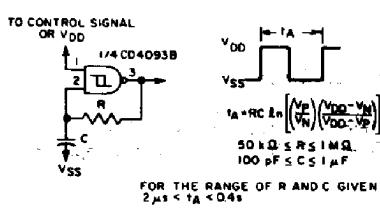
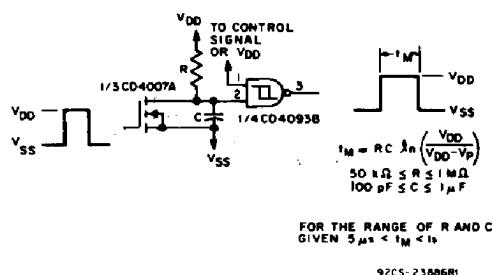
CD4093B Types



APPLICATIONS



FREQUENCY RANGE OF WAVE SHAPE IS FROM DC TO 1 MHz



Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

Dimensions and Pad Layout for CD4093BH

